

UNISONIC TECHNOLOGIES CO., LTD

MGBR20U50C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

■ DESCRIPTION

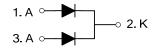
The UTC **MGBR20U50C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

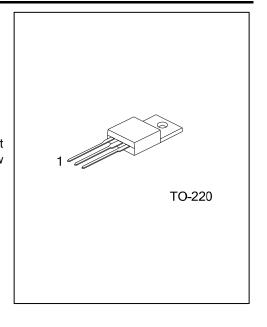
The UTC MGBR20U50C suitable for supply applications.

■ FEATURES

- * Ultra low forward voltage drop
- * High switching speed



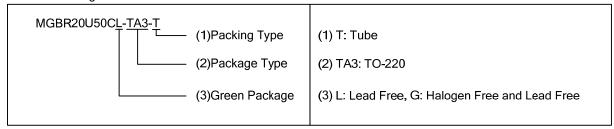




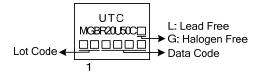
■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Packing	
Lead Free	Halogen Free	Package	1	2	3	Facking	
MGBR20U50CL-TA3-T	MGBR20U50CG-TA3-T	TO-220	Α	K	Α	Tube	

Note: Pin Assignment: A: Anode K: Cathode



■ MARKING



<u>www.unisonic.com.tw</u> 1 of 3

■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V_{RM}	50	V
Working Peak Reverse Voltage		V_{RWM}	50	٧
Peak Repetitive Reverse Voltage		V_{RRM}	50	V
Average Rectified Forward Current	Per Leg		10	Α
(Rated VR-20Khz Square Wave) - 50% Duty Cycle	Total	l _o	20	Α
Peak Forward Surge Current - 1/2 60hz		I _{FSM}	250	Α
Peak Repetitive Reverse Surge Current (2uS-1Khz)		I_{RRM}	2	Α
Maximum Rate of Voltage Change (at Rated V _R)		dv/dt	10000	V/µS
Operating Junction Temperature		T_J	-65~+150	°C
Storage Junction Temperature		T _{STG}	-65~+150	Ô

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ_{JC}	2	°C/W

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A=25°C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA	50			V
Forward Voltage	VEM	I _F =10A, T _J =25°C			0.45	V
		I _F =10A, T _J =125°C			0.40	V
Reverse Current (Note 1)	PM.	V _R =50V, T _J =25°C			500	μΑ
		V _R =50V, T _J =125°C			100	mΑ

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

